## NSN 5961-01-056-3303

**Fiig:** A110a0

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View Online at https://aerobasegroup.com/nsn/5961-01-056-3303 **Inclosure Material:** Metal **Overall Length:** Between 0.165 inches and 0.185 inches **Terminal Length:** 0.300 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage, dc all transistor and 80.0 collector to emitter voltage, dc all transistor and 5.0 emitter to base voltage, instantaneous all transistor **Current Rating Per Characteristic:** 1.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector absolute all transistor **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No